NCE1520KA

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE1520KA uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

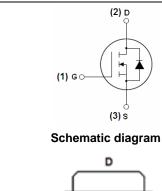
- V_{DS} = 150V, I_{D} =20A $R_{DS(ON)}$ <85mΩ @ V_{GS} =10V (Typ:70mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Boost converters
- LED backlighting
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!





Marking and pin assignment



TO-252 -2Ltop view

Package Marking and Ordering Information

	<u> </u>				
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE1520KA	NCE1520KA	TO-252-2L	_	-	-

Absolute Maximum Ratings (T_C=25 ℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
V _{DS}	Drain-Source Voltage	150	V
V _G s	Gate-Source Voltage	±20	V
I_{D}	Drain Current-Continuous	20	А
I _D (100℃)	Drain Current-Continuous(TC=100℃)	14	Α
I _{DM}	Pulsed Drain Current	40	Α
P _D	Maximum Power Dissipation	75	W
	Derating factor	0.5	W/°C
E _{AS}	Single pulse avalanche energy (Note 5)	200	mJ
T_{J}, T_{STG}	Operating Junction and Storage Temperature Range	-55 To 175	°C

Thermal Characteristic

R _{θJC}	Thermal Resistance, Junction-to-Case (Note 2)	2.0	°C/W

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Electrical Characteristics (T_C=25 °C unless otherwise noted)

Sy	mbol	Parameter	Condition	Min	Тур	Max	Unit
Off Characteristics							
BV _{DSS}	Drain-Source Break	down Voltage	00 1 2 11		165	-	V
I _{DSS}	Zero Gate Voltage	Drain Current	V _{DS} =150V,V _{GS} =0V	-	-	1	μΑ
I _{GSS}	Gate-Body Leaka	age Current	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics	(Note 3)						
V _{GS(th)}	Gate Threshold	d Voltage	V _{DS} =V _{GS} ,I _D =250μA 1.2		1.6	2.5	V
R _{DS(ON)}	Drain-Source On-Sta	ate Resistance	V _{GS} =10V, I _D =10A	-	70	85	mΩ
g FS	Forward Transco	nductance	V _{DS} =5V,I _D =10A	-	20	-	S
Dynamic Character	istics (Note4)						
C _{lss}	Input Capac	itance)/ 05)/)/ 0)/	-	2500	-	PF
Coss	Output Capa	citance	V _{DS} =25V,V _{GS} =0V,	-	326	-	PF
C _{rss}	Reverse Transfer	Capacitance	F=1.0MHz	-	202	-	PF
Switching Characte	eristics (Note 4)			•	•		
t _{d(on)}	Turn-on Dela	y Time		-	10.5	-	nS
t _r	Turn-on Rise	e Time	V_{DD} =75 V , R_L =5 Ω	-	5.5	-	nS
$t_{d(off)}$	Turn-Off Dela	ay Time	V_{GS} =10V, R_{GEN} =3 Ω	-	14.5	-	nS
t _f	Turn-Off Fal	I Time		-	3	-	nS
Qg	Total Gate C	Charge	\/ 75\/ L 40A	-	18	-	nC
Q _{gs}	Gate-Source	Charge	V _{DS} =75V,I _D =10A,	-	4.1	-	nC
Q _{gd}	Gate-Drain (Charge	V _{GS} =10V	-	4.5	-	nC
Drain-Source Diode	e Characteristics			•			
V _{SD}	Diode Forward Vo	oltage (Note 3)	V _{GS} =0V,I _S =20A	-	-	1.2	V
Is	Diode Forward C		-	-	-	20	Α
t _{rr}	Reverse Recov	ery Time	TJ = 25°C, IF = 10A	-	32	-	nS
Qrr	Reverse Recove	ry Charge	di/dt = 100A/µs ^(Note3)	-	53	-	nC
t _{on}	Forward Turn-0	On Time	Intrinsic turn-on time is negligible (turn-on is dominated by LS-				

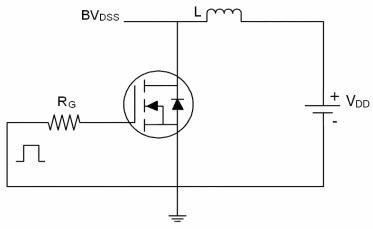
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition:Tj=25 $^{\circ}\text{C}$,V $_{DD}$ =50 V,V $_{G}$ =10 V,L=0.5 mH,Rg=25 Ω

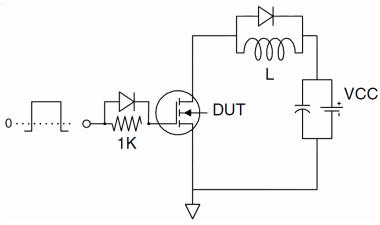
NCE1520KA

Test Circuit

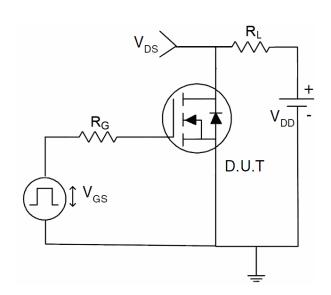
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

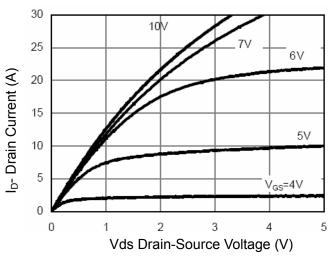


Figure 1 Output Characteristics

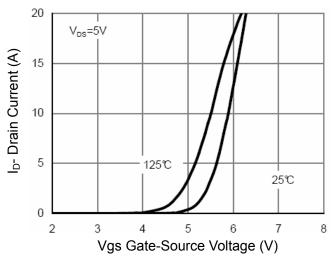


Figure 2 Transfer Characteristics

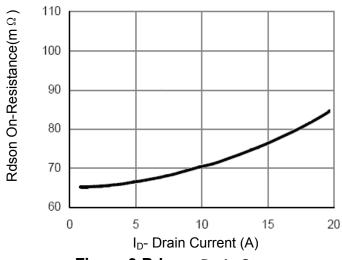


Figure 3 Rdson- Drain Current

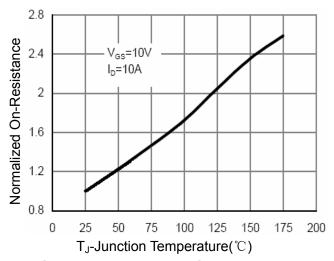
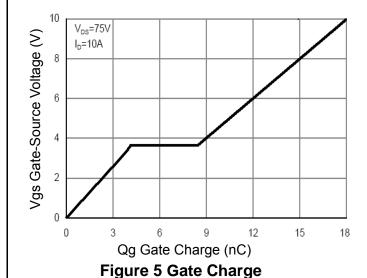


Figure 4 Rdson-JunctionTemperature



1.0E+02 € 1.0E+01 Reverse Drain Current 1.0E+00 1.0E-01 125℃ 1.0E-02 1.0E-03 25℃ 1.0E-04 <u>'</u>s 1.0E-05 0.2 0.4 0.6 1.0 1.2

Vsd Source-Drain Voltage (V)

Figure 6 Source- Drain Diode Forward



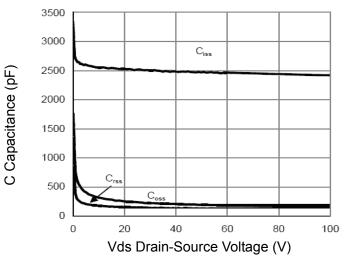


Figure 7 Capacitance vs Vds

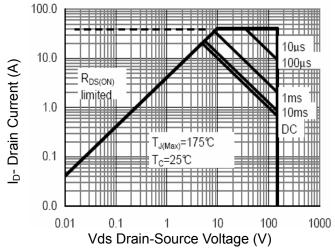


Figure 8 Safe Operation Area

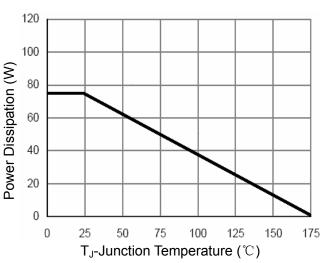


Figure 9 Power De-rating

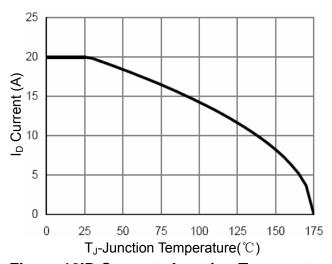


Figure 10ID Current- Junction Temperature

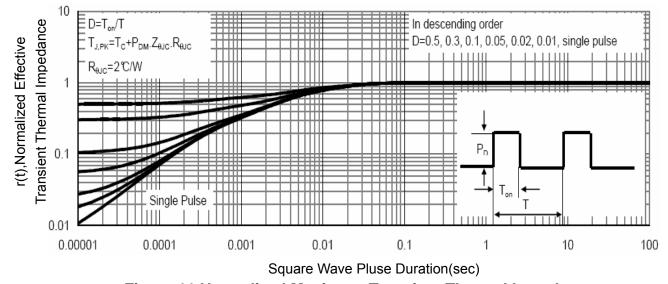
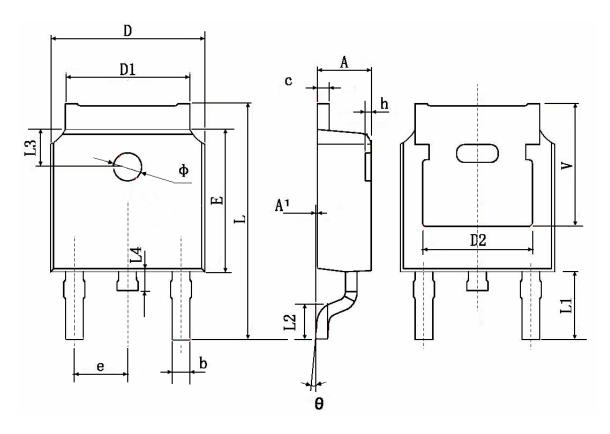


Figure 11 Normalized Maximum Transient Thermal Impedance

Pb Free Product



TO-252 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483 TYP.		0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.90	0 TYP.	0.114	0.114 TYP.	
L2	1.400	1.700	0.055	0.067	
L3	1.60	1.600 TYP.		TYP.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP.		0.211 TYP.		



http://www.ncepower.com

NCE1520KA

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